NSN 5962-01-371-1026

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View Online at https://aerobasegroup.com/nsn/5962-01-371-1026

Body Length:

Between 0.540 inches and 0.560 inches

Body Width:

Between 0.442 inches and 0.458 inches

Body Height:

Between 0.060 inches and 0.120 inches

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

5895-01-305-8863 recorder, signal data

Features Provided:

Programmed and burn in and 3-state output and w/buffered output and w/enable and w/disable and electrostatic sensitive

Inclosure Material:

Ceramic

Inclosure Configuration:

Leadless flat pack

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

13 input

Case Outline Source And Designator:

C-12 mil-m-38510

Current Rating Per Characteristic:

15.00 milliamperes reverse current, dc absolute

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Capitance Rating Per Characteristic:

10.00 input picofarads and 12.00 output picofarads

Time Rating Per Chacteristic:

120.00 nanoseconds access

Memory Device Type:

Prom

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

30 leadless

Shelf Life:

N/a

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Demilitarization:

Yes - demil/mli

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